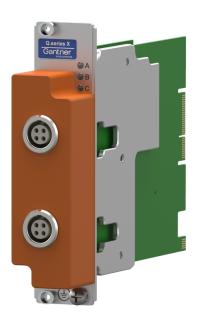


High Isolation Multi-Purpose Module

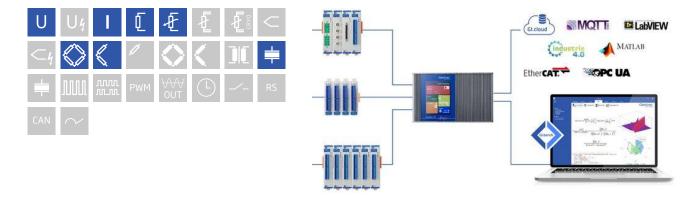
Q.raxx XL is a new addition to the Q.series product family - the ideal 19" rackmount DAQ solution for applications that require high channel density and custom sensor terminations. Q.raxx XL DAQ systems can utilize an integrated, high-performance controller for communication, control, and data logging purposes. With a controller, multiple Q.raxx XL systems can be synchronized to each other allowing for efficient DAQ distribution with low jitter and gradual expansion up to thousands of channels.

- High Density up to 13 I/O modules per Q.raxx 3U chassis with up to 16 channels per I/O module
- User Friendly front panel indicators for module status, power, and input range error
- Fully Customizable multiple front panel termination options available
- Maximum Flexibility parallel communication available in TCP/IP, CAN, PROFIBUS, Modbus, and EtherCAT
- Gantner's Quality Standard integrated filtering, galvanic isolation & signal/sensor conditioning per channel



Key Features

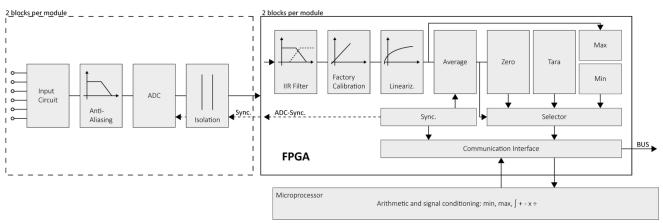
- 2 high galvanic isolated input channels voltage, current, Pt100, potentiometer, full- and half bridges, IEPE, isolation voltage 1200 VDC permanent
- Signal conditioning linearization, digital filter, average, scaling, min/max storage, arithmetic, alarm
- Fast high accuracy digitalization
 24 bit ADC, 100 kHz sample rate each channel
- Galvanic isolation channel to channel to power supply and to interface
- Categories
 1000 V CAT II and 600 V CAT III



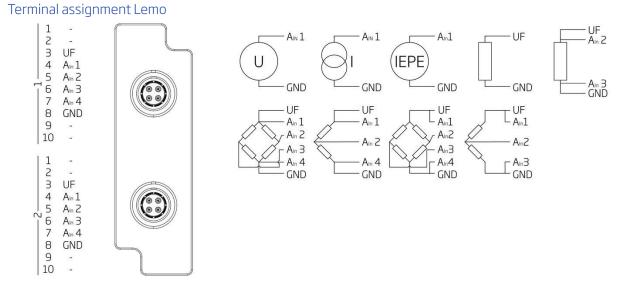


High Isolation Multi-Purpose Module

Block diagram



Technical Data



Mounting socket: LEMO EGG.2B.436.CJA Mating connector: FGG.2B.436.CJLD52Z

Analog Inputs

Channels	2
Isolation voltage	1200 VDC continuous, channel to channel to power supply channel to bus



High Isolation Multi-Purpose Module

Measurement Mode Voltage

	Range	Margin of error	Resolution
Free	±10 V	±2 mV	1.2 μV
Error	±1V	±0.2 mV	120 nV
	±100 mV	±20 μV	12 nV
Input impedance	>10 MΩ		
Long-term drift	<20 µV / 24 h	<200 µV/8000 h	
To mo oraști no 1-9	Offset drift	Gain drift	
Temperature influence	<50 µV/10 K	<0.2%/10K	
Signal-to-noise ratio	>100 dB at 100 Hz		

Measurement Mode Current

Error	range	max. error	resolution
Internal shunt resistor 50 Ω	±25 mA	±5 μA	3.0 nA
Long-term drift	<0.5 µA / 24 h	<5 µA / 8000 h	
To man a wate was in flore a se	Offset drift	Gain drift	
Temperature influence	<1 µA / 10 K	<0.025 % / 10 K	

Measurement Mode Resistance / RTD

Error	range	max. error	resolution
Resistance, 2-wire	100 kΩ	±100 Ω	12 mΩ
Resistance, 2- and 4-wire	4 kΩ	±lΩ	0.5 mΩ
Resistance, 2- and 4-wire	400 Ω	±0.1Ω	48 μΩ
Pt100, 2- and 4-wire	-200 to +850°C	±0.25°C	0.2 m°C
Pt1000, 2- and 4-wire	-200 to +850°C	±1°C	0.2 m°C
Long-term drift	<0.01°C/24 h	<0.1°C/8000 h	
Tomporature influence	Offset drift (range 400 Ω)	Gain drift	
Temperature influence	<10 mΩ / 10 K	<0.025 % / 10 K	

Measurement Mode Potentiometer

Allowable potentiometer resistance	1 kΩ to 10 kΩ	
Long-term drift	<0.01 % / 24 h	<0.1 % / 8000 h
Tomporatura influence	Offset drift	Gain drift
Temperature influence	<0.0001/10K	<0.02 % / 10 K

Measurement Mode Bridge

Bridge configuration(s)	half- and full-bridge, 5-/6-wire	
Accuracy class	0.05	
Bridge resistance	>100 Q	
Bridge excitation	2.5 VDC, nominal	
Measurement range	±2.5 mV/V, ±5 mV/V, ±10 mV/V, ±25 mV/V, ±500 mV/V	
Long-term drift	<0.12 µV/V / 24 h	<1.2 µV/V / 8000 h
	Offset drift	Gain drift
Temperature influence	<0.2 µV/V / 10 K	<0.05 % / 10 K



High Isolation Multi-Purpose Module

Measurement Mode IEPE Sensor

	range	max. error	resolution
Error	±10 V	±10 mV	1.2 μV
	±1V	±1 mV	120 nV
Supply	constant current 4 mA		
Input frequency range	0.5 Hz to 10 kHz		
Tomporature influence	Offset drift (range 10 V)	Gain drift	
Temperature influence	<10 µV / 10 K	<0.025%/10K	

Analog/Digital Conversation

Resolution	24-bit
Update rate	100 kHz (measurement thermocouple 8 Hz)
Modulation method	Sigma-Delta
Anti-aliasing filter	20 kHz, 3rd order
Digital filters	Infinite impulse response (IIR), low-pass, high-pass, band-pass, Butterworth or Bessel (2nd, 4th, 6th or 8th order), frequency range 0.1 Hz to 10 kHz (adjustable via software)
Averaging	configurable or automatic according to the selected data rate

Communication Interface Localbus

Protocols	proprietary Localbus (115200 bps to 48 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU
Data format	8E1
Electrical standard	ANSI/TIA/EIA-485-A, 2-wire

Power Supply

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	approx 2 W
Input voltage influence	<0.001 %/V

Environmental

Operating temperature	-20°C to +60°C
Storage temperature	-40°C to +85°C
Relative humidity	5 % to 95 % at 50°C, non-condensing
Pollution degree	1

Remarks

Are subject to a warm-up period of at least 45 minutes	
in a controlled electromagnetic environment ¹	
With configuration: Low-pass 10Hz²	
Specifications subject to change without notice	

1 according to EN 61326 2006: appendix B

² according to EN 61326 2006: appendix A



High Isolation Multi-Purpose Module

High Voltage Warnings



- Attention! High voltage device! Danger to life and health in case of non regular use.
- Only special and sufficient educated persons are permitted to handle this device only.
- All metal housing parts must be safe and permanently connected to protected earth PE.
- Only contact protection plugs and cables may be used. All parts must be approved for voltages up to 1200 VDC.
- During installation, the whole system must be without voltage and safely be disconnected from the mains.
- All relevant safety regulations must be considered.
- Do not operate with damaged casing.

Base is the european standard EN61010-1

Mechanical information

Material	Aluminum
Measurements (W x H x D)	30x 128 x 150mm
Weight	approx. 200 g

Ordering Information

Article number 577431

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